

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

HN1B01F

Audio-Frequency General-Purpose Amplifier Applications

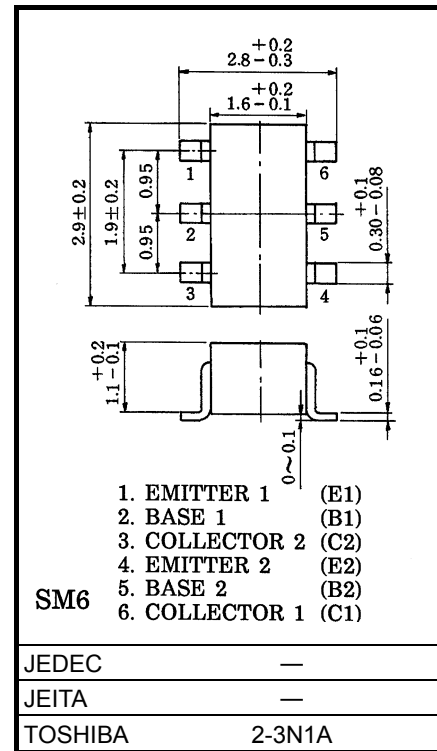
Unit: mm

Q1:

- High voltage and high current
: $V_{CE0} = -50\text{ V}$, $I_C = -150\text{ mA}$ (max)
- High h_{FE} : $h_{FE} = 120$ to 400
- Excellent h_{FE} linearity
: $h_{FE}(I_C = -0.1\text{ mA}) / h_{FE}(I_C = -2\text{ mA}) = 0.95$ (typ.)

Q2:

- High voltage and high current
: $V_{CE0} = 50\text{ V}$, $I_C = 150\text{ mA}$ (max)
- High h_{FE} : $h_{FE} = 120$ to 400
- Excellent h_{FE} linearity
: $h_{FE}(I_C = 0.1\text{ mA}) / h_{FE}(I_C = 2\text{ mA}) = 0.95$ (typ.)

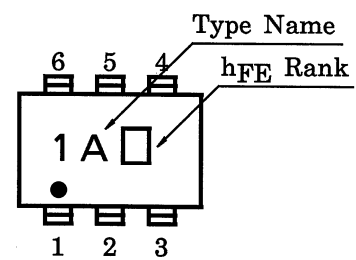


Weight: 0.015 g (typ.)

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-150	mA
Base current	I_B	-50	mA

Marking

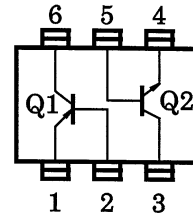


Start of commercial production
1989-02

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I _C	150	mA
Base current	I _B	30	mA

Equivalent Circuit (Top View)



Q1, Q2 Common Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector power dissipation	P _C *	300	mW
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-55 to 125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

*: Total rating

Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CBO}	—	V _{CB} = -50 V, I _E = 0	—	—	-0.1	μA
Emitter cut-off current	I _{EBO}	—	V _{EB} = -5 V, I _C = 0	—	—	-0.1	μA
DC current gain	h _{FE} (Note)	—	V _{CE} = -6 V, I _C = -2 mA	120	—	400	
Collector-emitter saturation voltage	V _{CE(sat)}	—	I _C = -100 mA, I _B = -10 mA	—	-0.1	-0.3	V
Transition frequency	f _T	—	V _{CE} = -10 V, I _C = -1 mA	—	120	—	MHz
Collector output capacitance	C _{ob}	—	V _{CB} = -10 V, I _E = 0, f = 1 MHz	—	4	—	pF

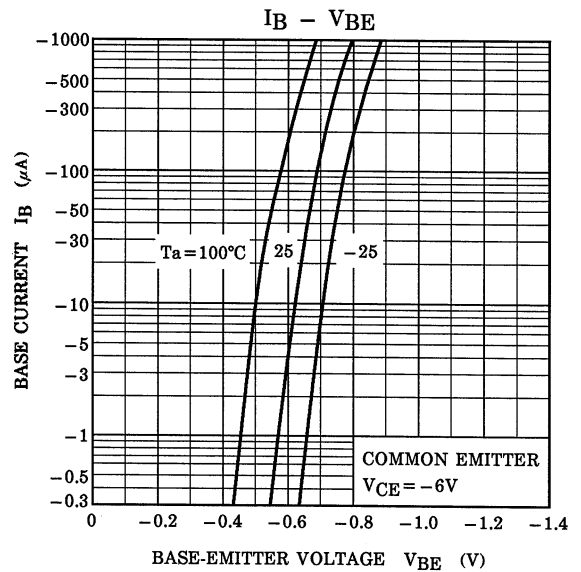
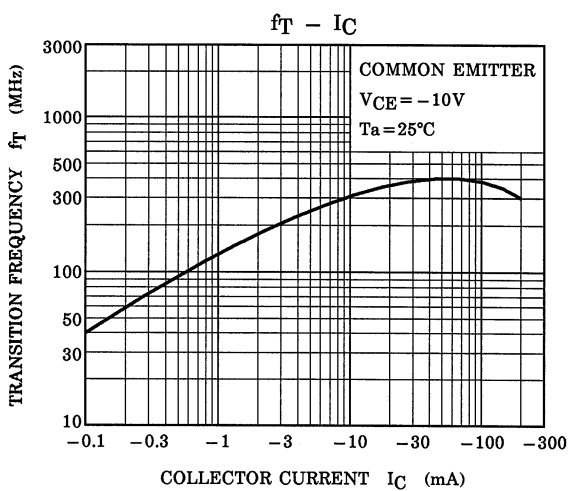
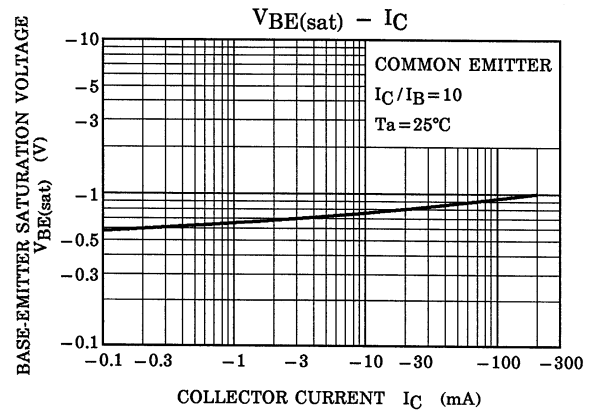
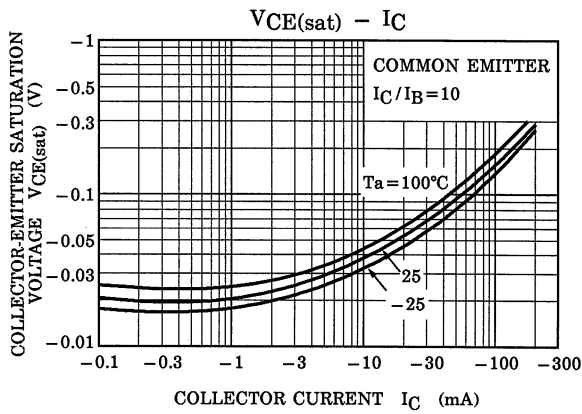
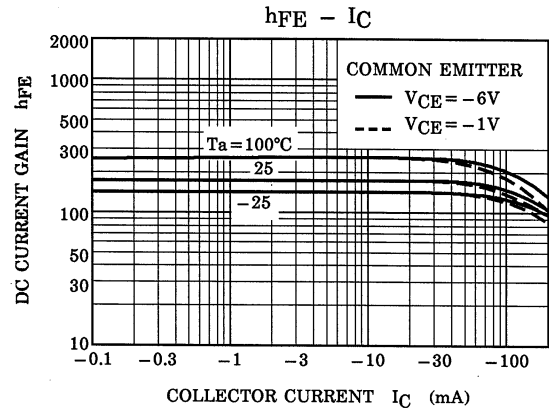
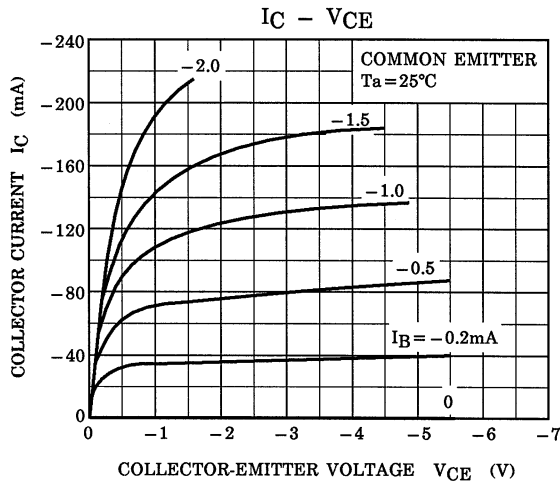
Q2 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CBO}	—	V _{CB} = 60 V, I _E = 0	—	—	0.1	μA
Emitter cut-off current	I _{EBO}	—	V _{EB} = 5 V, I _C = 0	—	—	0.1	μA
DC current gain	h _{FE} (Note)	—	V _{CE} = 6 V, I _C = 2 mA	120	—	400	
Collector-emitter saturation voltage	V _{CE(sat)}	—	I _C = 100 mA, I _B = 10 mA	—	0.1	0.25	V
Transition frequency	f _T	—	V _{CE} = 10 V, I _C = 1 mA	—	150	—	MHz
Collector output capacitance	C _{ob}	—	V _{CB} = 10 V, I _E = 0, f = 1 MHz	—	2	—	pF

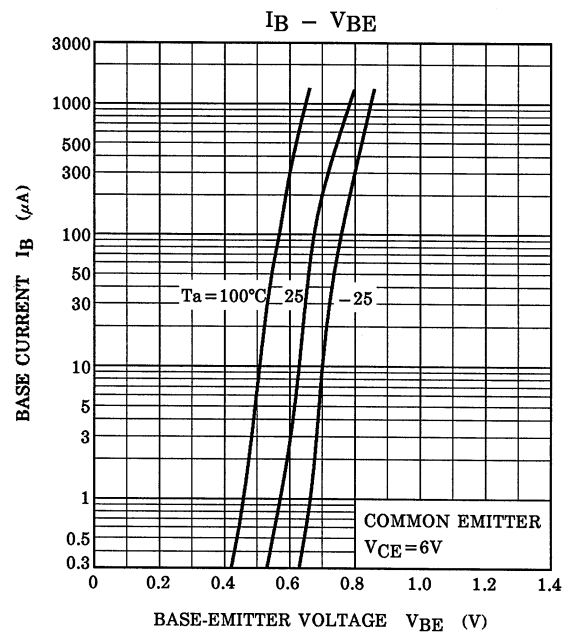
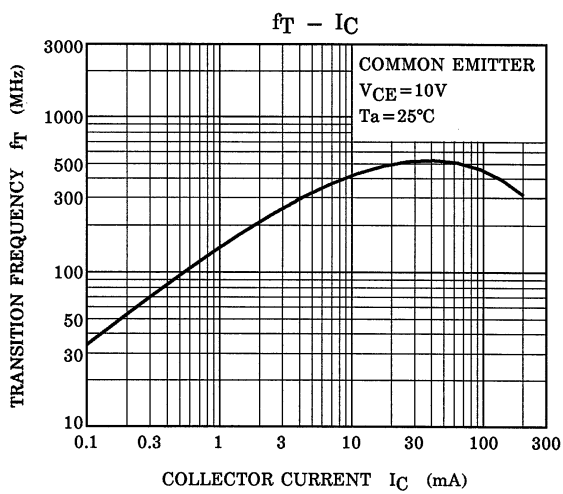
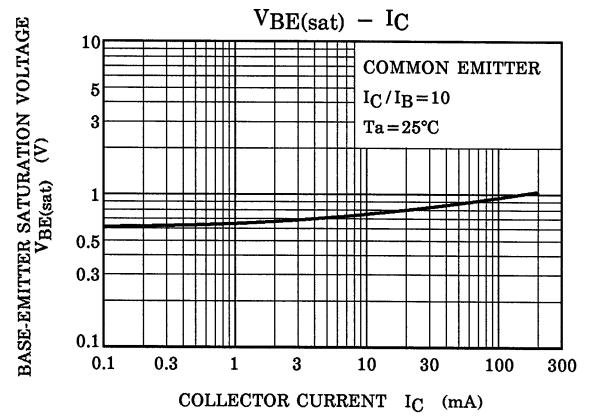
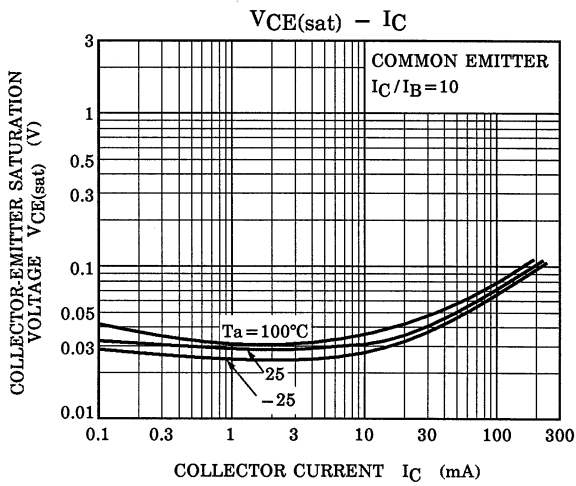
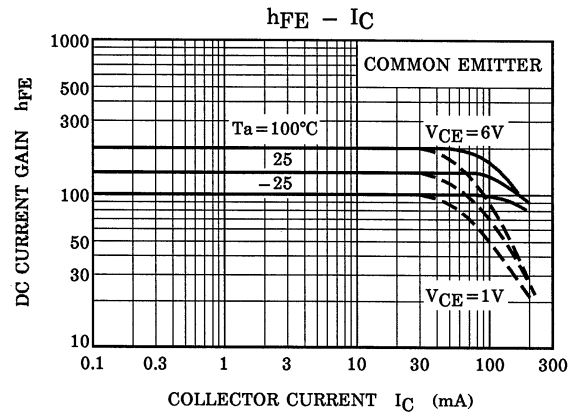
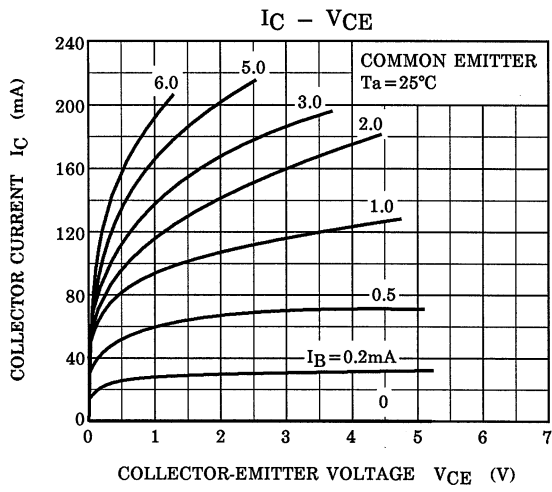
Note: h_{FE} Classification Y (Y): 120 to 240, GR (G): 200 to 400

() Marking symbol

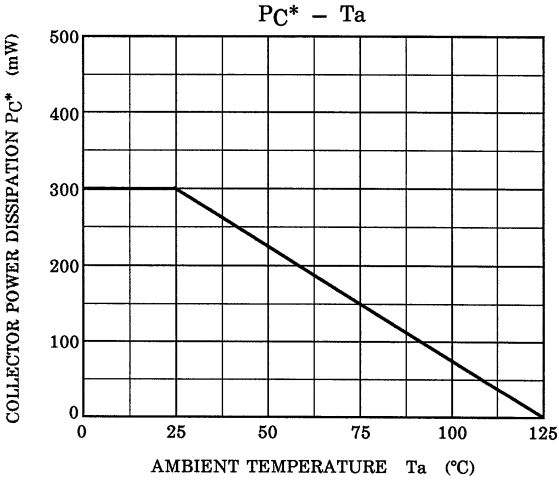
Q1 (PNP Transistor)



Q2 (NPN Transistor)



(Q1, Q2 Common)



* : Total Rating

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